

LP5521 **Programmable Three Channel LED Driver**

General Description

The LP5521 is a three channel LED driver designed to produce variety of lighting effects for mobile devices. High efficiency charge pump enables LED driving over full Li-Ion battery voltage range. The device has a program memory for creating variety of lighting sequences. When program memory has been loaded, LP5521 can operate independently without processor control.

LP5521 maintains excellent efficiency over a wide operating range by automatically selecting proper charge pump gain based on LED forward voltage requirements. LP5521 is able to automatically enter power-save mode, when LED outputs are not active and thus lowering current consumption.

Three independent LED channels have accurate programmable current sources and PWM control. Each channel has program memory for creating desired lighting sequences with PWM control.

LP5521 has a flexible digital interface. Trigger I/O and 32 kHz clock input allow synchronization between multiple devices. Interrupt output can be used to notify processor, when LED sequence has ended. LP5521 has four pin selectable I²C addresses. This allows connecting up to four parallel devices in one I²C bus. GPO and INT pins can be used as a digital control pin for other devices.

LP5521 requires only four small and low cost ceramic capacitors.

LP5521 is available in tiny 2.1x1.7x0.6 mm microSMD-20 package and in 4.0x5.0x0.8 mm bumped LLP-24 package.

Comprehensive application tools are available, including command compiler for easy LED sequence programming.

Typical Application

Features

- Adaptive charge pump with 1x and 1.5x gain provides up to 95% LED drive efficiency
- Charge pump with soft start and overcurrent/short circuit protection
- Low input ripple and EMI
- Very small solution size, no inductor or resistors required
- 200 nA typical shutdown current
- Automatic power save mode
- I²C compatible interface
- -Independently programmable constant current outputs with 8-bit current setting and 8-bit PWM control
- Typical LED output saturation voltage 50 mV and current matching 1%
- Three program execution engines with flexible instruction set
- Autonomous operation without external control
- Large SRAM program memory
- Two general purpose digital outputs
- microSMD-20 package, 0.4 mm pitch
- Bumped LLP-24 package, 0.5 mm pitch

Applications

- Fun / indicator lights
- LCD sub-display backlighting
- Keypad RGB backlighting and phone cosmetics
- Vibra, speakers, waveform generator



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Pin Descriptions LP5521TM

Pin #	Name	Туре	Description	
1A	В	А	Current source output	
1B	G	А	Current source output	
1C	R	А	Current source output	
1D	SCL	I	I ² C Serial interface clock input	
1E	SDA	I/OD	I ² C Serial interface data input/output	
2A	VOUT	А	Charge pump output	
2B	ADDR_SEL1	I	I ² C address select input	
2C	ADDR_SEL0	I	I ² C address select input	
2D	GPO	0	General purpose output	
2E	EN		Chip enable	
ЗA	CFLY2N	А	Negative terminal of charge pump fly capacitor 2	
3B	CFLY1N	А	Negative terminal of charge pump fly capacitor 1	
ЗC	GND	G	Ground	
3D	CLK_32K	I	32 kHz clock input	
3E	INT	OD/O	Interrupt output / General Purpose Output	
4A	CFLY2P	А	Positive terminal of charge pump fly capacitor 2	
4B	CFLY1P	А	Positive terminal of charge pump fly capacitor 1	
4C	VDD	Р	Power supply pin	
4D	GND	G	Ground	
4E	TRIG	I/OD	Trigger input/output	

A: Analog Pin, G: Ground Pin, P: Power Pin, I: Input Pin, I/O: Input/Output Pin, O: Output Pin, OD: Open Drain Pin

Pin Descriptions LP5521YQ

Pin #	Name	Туре	Description
1	CFLY2P	A	Positive terminal of charge pump fly capacitor 2
2	CFLY1P	А	Positive terminal of charge pump fly capacitor 1
3	VDD	Р	Power supply pin
4	GND	G	Ground
5	CLK_32K	I	32 kHz clock input
6	INT	OD/O	Interrupt output / General purpose output
7	TRIG	I/OD	Trigger input/output
8		N/C	
9		N/C	
10		N/C	
11		N/C	
12		N/C	
13	SDA	I/OD	I ² C Serial interface data input/output
14	EN	I	Chip enable
15	SCL	I	I ² C Serial interface clock input
16	GPO	0	General purpose output
17	R	A	Current source output
18	G	A	Current source output
19	В	A	Current source output
20	ADDR_SEL0	I	I ² C address select input
21	ADDR_SEL1	I	I ² C address select input
22	VOUT	А	Charge pump output
23	CFLY2N	A	Negative terminal of charge pump fly capacitor 2
24	CFLY1N	А	Negative terminal of charge pump fly capacitor 1

A: Analog Pin, G: Ground Pin, P: Power Pin, I: Input Pin, I/O: Input/Output Pin, O: Output Pin, OD: Open Drain Pin, N/C: Not Connected

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Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

V(V _{DD} , V _{OUT} , R, G, B)	-0.3V to +6.0V
Voltage on Logic Pins	-0.3V to V _{DD} +0.3V
	with 6.0V max
Continuous Power Dissipation (Note 3)	Internally Limited
Junction Temperature (T _{J-MAX})	125°C
Storage Temperature Range	-65°C to +150°C
Maximum Lead Temperature (Soldering)	(Note 4)
ESD Rating (Note 5) Human Body Model: Machine Model:	2 kV 200V

Operating Ratings (Notes 1, 2)

V _{DD}	2.7 to 5.5V
Recommended Charge Pump Load Current I _{OUT}	0 to 100 mA
Load Ourient IOUT	0 10 100 IIIA
Junction Temperature (T _J) Range	-30°C to +125°C
Ambient Temperature (T _△) Range	
(Note 6)	-30°C to +85°C
Thermal Properties	
Junction-to-Ambient Thermal	
Resistance (θ_{JA}), TMD20 Package	

(Note 7) 50 - 90°C/W Junction-to-Ambient Thermal Resistance (θ_{JA}), YQA24A Package (Note 7) 37 - 90°C/W

Electrical Characteristics (Notes 2, 8)

Limits in standard typeface are for $T_J = 25^{\circ}$ C. Limits in **boldface** type apply over the operating ambient temperature range (-30°C < $T_A < +85^{\circ}$ C). Unless otherwise noted, specifications apply to the LP5521 Block Diagram with: 2.7V $\leq V_{DD} \leq 5.5$ V, $C_{OUT} = C_{IN} = 1 \ \mu$ F, $C_{FLY1} = C_{FLY2} = 0.47 \ \mu$ F. (Note 9).

Symbol	Parameter	Condition	Min	Тур	Max	Units
I _{VDD} Standby current	Standby supply current	EN = 0 (pin), CHIP_EN = 0 (bit), external 32 kHz clock running or not running		0.2	2	μA
		EN = 1 (pin), CHIP_EN = 0 (bit), external 32 kHz clock not running		1.0		μA
		EN = 1 (pin), CHIP_EN = 0 (bit), external 32 kHz clock running		1.4		μA
	Normal mode	Charge pump and LED drivers disabled		0.25		mA
	supply current	Charge pump in 1x mode, no load, LED drivers disabled		0.70		mA
		Charge pump in 1.5x mode, no load, LED drivers disabled		1.5		mA
		Charge pump in 1x mode, no load, LED drivers enabled		1.2		mA
	Powersave mode	External 32 kHz clock running		10		μA
	supply current	Internal oscillator running		0.25		mA
f _{osc}	Internal oscillator frequency accuracy		-4 -7		4 7	%

Charge Pump Electrical Characteristics (Note 10)

Symbol	Parameter	Condition	Min	Тур	Max	Units
R _{OUT}	Charge pump output resistance	Gain = 1.5x		3.5		Ω
		Gain = 1x		1		Ω
f _{SW}	Switching frequency			1.25		MHz
			-7		7	%
I _{GND}	Ground current	Gain = 1.5x		1.2		mA
		Gain = 1x		0.5		mA
+				100		
LON	off to 1.5x mode	I _{OUT} = 60 mA		100		μs
V _{OUT}	Charge pump output voltage	$V_{DD} = 3.6V$, no load, Gain = 1.5x		4.55		V

Symbol	Parameter	Condition		Min 1	Гур Мах	Units
LEAKAGE	R, G, B pin leakage current				D.1 1	μΑ
МАХ	Maximum Source Current	Outputs R, G, B		2	5.5	mA
OUT	Accuracy of output current	Output current set to 17.5 mA, V _{DD} = 3.6V		-4 -5	4	%
матсн	Matching (Note 11)	I _{OUT} = 17.5 mA, V _{DD} = 3.6V			1 2	%
LED	LED PWM switching frequency	PWM_HF = 1 Frequency defined by internal os	cillator	Ę	558	Hz
		PWM_HF = 0 Frequency defined by 32 kHz clo external)	ck (internal or	2	256	Hz
V _{SAT}	Saturation voltage (Note 12)	I _{OUT} set to 17.5 mA			50 100	mV
Symbol .OGIC IN	Parameter PUT EN	Conditions	Min	Тур	Max	Units
				.) P		
/ _{IL}	Input Low Level				0.5	V
/ _{IH}	Input High Level		1.2			V
I	Logic Input Current		-1.0		1.0	μA
DELAY	Input delay			2		μs
OGIC IN	PUT SCL, SDA, TRIG, CLK_32K					
V _{IL}	Input Low Level				0.2xV(EN)	V
/ _{IH}	Input High Level		0.8xV(EN)			V
I	Input Current		-1.0		1.0	μA
CLK_32K	Clock frequency			32		kHz
SCL	Clock frequency				400	kHz
OGIC O	JTPUT SDA, TRIG, INT					
/ _{OL}	Output Low Level	I _{OUT} = 3 mA (pull-up current)		0.3	0.5	V
L	Output Leakage Current				1.0	μA
	PUT ADDR_SEL0, ADDR_SEL1				-	
/ _{IL}	Input Low Level				0.2xV _{DD}	V
/ _{IH}	Input High Level		0.8xV _{DD}			V
I	Input Current		-1.0		1.0	μA
	JTPUT GPO, INT (in GPO state)					
/ _{OL}	Output Low Level	I _{OUT} = 3 mA		0.3	0.5	V
			11 05	V/ 0.0		
V _{OH}	Output High Level	I _{OUT} = -2 mA	V _{DD} - 0.5	V _{DD} - 0.3		V

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I²C Timing Parameters (SDA, SCL) (Note 13)

Sumbol	Parameter	Lim	Limit	
Symbol	Parameter	Min	Max	– Units
f _{SCL}	Clock Frequency		400	kHz
1	Hold Time (repeated) START Condition	0.6		μs
2	Clock Low Time	1.3		μs
3	Clock High Time	600		ns
4	Setup Time for a Repeated START Condition	600		ns
5	Data Hold Time	50		ns
6	Data Setup Time	100		ns
7	Rise Time of SDA and SCL	20+0.1C _b	300	ns
8	Fall Time of SDA and SCL	15+0.1C _b	300	ns
9	Set-up Time for STOP condition	600		ns
10	Bus Free Time between a STOP and a START Condition	1.3		μs
Cb	Capacitive Load for Each Bus Line	10	200	pF



Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the component may occur. Operating Ratings are conditions under which operation of the device is guaranteed. Operating Ratings do not imply guaranteed performance limits. For guaranteed performance limits and associated test conditions, see the Electrical Characteristics tables.

Note 2: All voltages are with respect to the potential at the GND pins.

Note 3: Internal thermal shutdown circuitry protects the device from permanent damage. Thermal shutdown engages at $T_J = 150^{\circ}C$ (typ.) and disengages at $T_J = 130^{\circ}C$ (typ.).

Note 4: For detailed soldering specifications and information, please refer to National Semiconductor Application Note AN1112 : Micro SMD Wafer Level Chip Scale Package or AN1187 : Leadless Leadframe Package (LLP).

Note 5: The Human body model is a 100 pF capacitor discharged through a 1.5 kΩ resistor into each pin. The machine model is a 200 pF capacitor discharged directly into each pin. MIL-STD-883 3015.7

Note 6: In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may have to be derated. Maximum ambient temperature (T_{A-MAX}) is dependent on the maximum operating junction temperature $(T_{J-MAX-OP} = 125^{\circ}C)$, the maximum power dissipation of the device in the application (P_{D-MAX}) , and the junction-to ambient thermal resistance of the part/package in the application (θ_{JA}) , as given by the following equation: $T_{A-MAX} = T_{J-MAX-OP} - (\theta_{JA} \times P_{D-MAX})$.

Note 7: Junction-to-ambient thermal resistance is highly application and board-layout dependent. In applications where high maximum power dissipation exists, special care must be paid to thermal dissipation issues in board design.

Note 8: Min and Max limits are guaranteed by design, test, or statistical analysis. Typical numbers are not guaranteed, but do represent the most likely norm.

Note 9: Low-ESR Surface-Mount Ceramic Capacitors (MLCCs) used in setting electrical characteristics.

Note 10: Input, output, and fly capacitors should be of the type X5R or X7R low ESR ceramic capacitor.

Note 11: Matching is the maximum difference from the average of the three output's currents.

Note 12: Saturation voltage is defined as the voltage when the LED current has dropped 10% from the value measured at V_{OUT} - 1V. Note 13: Guaranteed by design.

Typical Performance Characteristics

Unless otherwise specified: $V_{DD} = 3.6V$















LED Current vs. Supply Voltage



Charge Pump Efficiency vs. Input Voltage 1.5x Mode









Charge Pump Load Transient Response in 1.5x Mode (0 to 25.5 mA)



20186214

Charge Pump Output Voltage vs. Input Voltage Automatic Gain Change from 1x to 1.5x



20186211

Charge Pump Startup in 1.5x Mode No Load



20186213

Charge Pump Line Transient Response 1.5x Mode (V_{IN} 3.5V to 4.0V)



TIME (200 µs/DIV)

20186215



For full LP5521 datasheet please contact nearest National Semiconductor sales office.



Notes

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